## International **IOR** Rectifier

Data Sheet No. PD60191 revD

## IR21091(S) & (PbF)

## HALF-BRIDGE DRIVER

#### **Features**

- Floating channel designed for bootstrap operation Fully operational to +600V Tolerant to negative transient voltage dV/dt immune
- Gate drive supply range from 10 to 20V
- Undervoltage lockout for both channels
- 3.3V, 5V and 15V input logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- High side output in phase with IN input
- Logic and power ground +/- 5V offset.
- Internal 500ns dead-time, and programmable up to 5us with one external R<sub>DT</sub> resistor
- Lower di/dt gate driver for better noise immunity
  The dual function DT/SD pin input turns off both
- channels.
- Available in Lead-Free

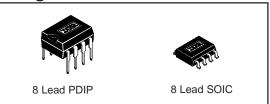
#### Description

The IR21091(S) are high voltage, high speed power MOSFET and IGBT drivers with dependant high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable rugge-

#### Product Summary

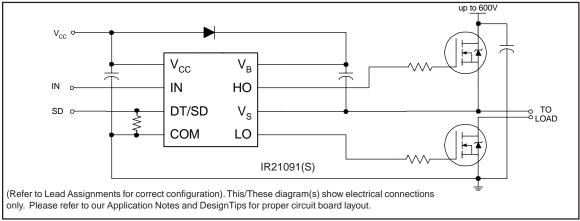
Voffset	600V max.
I <sub>O</sub> +/-	120 mA / 250 mA
Vout	10 - 20V
ton/off (typ.)	680 & 170 ns
Dead time	500 ns
(programmable u	p to 5uS)

#### Packages



dized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver crossconduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 volts.

#### **Typical Connection**



#### **Absolute Maximum Ratings**

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition		Min.	Max.	Units
VB	High side floating absolute voltage		-0.3	625	
Vs	High side floating supply offset voltage		V <sub>B</sub> - 25	V <sub>B</sub> + 0.3	
V <sub>HO</sub>	High side floating output voltage		V <sub>S</sub> - 0.3	V <sub>B</sub> + 0.3	
V <sub>CC</sub>	Low side and logic fixed supply voltage		-0.3	25	V
VLO	Low side output voltage		-0.3	V <sub>CC</sub> + 0.3	V
DT/SD	Programmable dead-time and shut-down pin voltage		V <sub>SS</sub> - 0.3	V <sub>CC</sub> + 0.3	
VIN	Logic input voltage		V <sub>SS</sub> - 0.3	V <sub>CC</sub> + 0.3	
dV <sub>S</sub> /dt	Allowable offset supply voltage transient		_	50	V/ns
PD	Package power dissipation @ $T_A \le +25^{\circ}C$	(8 Lead PDIP)	_	1.0	
		(8 Lead SOIC)	—	0.625	W
RthJA	Thermal resistance, junction to ambient	(8 Lead PDIP)	_	125	°C/W
		(8 Lead SOIC)	_	200	°C/VV
ТJ	Junction temperature		_	150	
Τ <sub>S</sub>	Storage temperature		-50	150	°C
TL	Lead temperature (soldering, 10 seconds)		_	300	

#### **Recommended Operating Conditions**

The input/output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. The  $V_S$  offset rating are tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
VB	High side floating supply absolute voltage	V <sub>S</sub> + 10	V <sub>S</sub> + 20	
VS	High side floating supply offset voltage	Note 1	600	
V <sub>HO</sub>	High side floating output voltage	VS	VB	
Vcc	Low side and logic fixed supply voltage	10	20	
VLO	Low side output voltage	0	V <sub>CC</sub>	v
V <sub>IN</sub>	Logic input voltage	V <sub>SS</sub>	V <sub>CC</sub>	
DT/SD	Programmable dead-time and shut-down pin voltage	V <sub>SS</sub>	V <sub>CC</sub>	
TA	Ambient temperature	-40	125	°C

Note 1: Logic operational for V<sub>S</sub> of -5 to +600V. Logic state held for V<sub>S</sub> of -5V to -V<sub>BS.</sub> (Please refer to the Design Tip DT97-3 for more details).

#### International **TOR** Rectifier

## IR21091(S) & (PbF)

#### **Dynamic Electrical Characteristics**

 $V_{BIAS}$  (V<sub>CC</sub>, V<sub>BS</sub>) = 15V, C<sub>L</sub> = 1000 pF, T<sub>A</sub> = 25°C, DT = VSS unless otherwise specified.

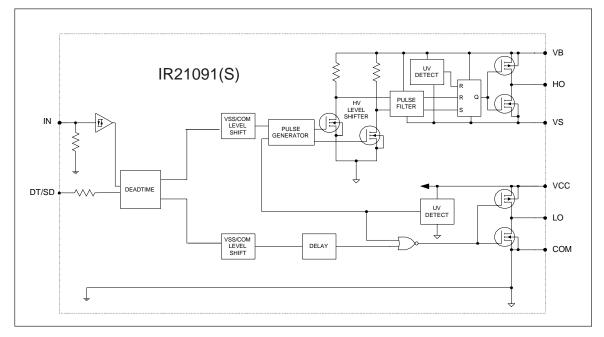
Symbol	Definition	Min.	Тур.	Max.	Units	<b>Test Conditions</b>
ton	Turn-on propagation delay	_	750	950		$V_{S} = 0V$
toff	Turn-off propagation delay	_	200	280		$V_{\rm S} = 0 V \text{ or } 600 V$
MT	Delay matching, HS & LS turn-on/off	_	0	70		
tr	Turn-on rise time	_	150	220	nsec	$V_{S} = 0V$
tf	Turn-off fall time	_	50	80		$V_{\rm S} = 0V$
DT	Deadtime: LO turn-off to HO turn-on(DTLO-HO) &	400	540	680		RDT= 0
	HO turn-off to LO turn-on (DT <sub>HO-LO)</sub>	4	5	6	usec	RDT = 200k
MDT	Deadtime matching = DTLO - HO - DTHO-LO		0	60		RDT=0
		—	0	600	nsec	RDT = 200k
tsd	Shut down propagation delay	215		615		

#### **Static Electrical Characteristics**

 $V_{BIAS}$  (V<sub>CC</sub>, V<sub>BS</sub>) = 15V, DT= V<sub>SS</sub> and T<sub>A</sub> = 25°C unless otherwise specified. The V<sub>IL</sub>, V<sub>IH</sub> and I<sub>IN</sub> parameters are referenced to V<sub>SS</sub> /COM and are applicable to the respective input leads: IN and DT. The V<sub>O</sub>, I<sub>O</sub> and Ron parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

Symbol	Definition	Min.	Тур.	Max.	Units	<b>Test Conditions</b>
VIH	Logic "1" input voltage for HO & logic "0" for LO	2.9	_	-		$V_{CC} = 10V \text{ to } 20V$
VIL	Logic "0" input voltage for HO & logic "1" for LO	_	_	0.8		$V_{CC} = 10V$ to 20V
V <sub>SD,TH</sub>	DT/SD pin shutdown input threshold	11.5	13	14.5		
V <sub>OH</sub>	High level output voltage, V <sub>BIAS</sub> - V <sub>O</sub>	—	0.8	1.4	V	I <sub>O</sub> = 20 mA
V <sub>OL</sub>	Low level output voltage, VO	-	0.3	0.6		I <sub>O</sub> = 20 mA
I <sub>LK</sub>	Offset supply leakage current	-	_	50	μA	$V_{B} = V_{S} = 600V$
I <sub>QBS</sub>	Quiescent V <sub>BS</sub> supply current	20	60	150	μΛ	$V_{IN} = 0V \text{ or } 5V$
IQCC	Quiescent V <sub>CC</sub> supply current	0.4	1.0	1.6	mA	$V_{IN} = 0V \text{ or } 5V$
						RDT = 0
I <sub>IN+</sub>	Logic "1" input bias current	-	5	20	μA	IN = 5V, SD = 0V
I <sub>IN-</sub>	Logic "0" input bias current	-	1	2		$IN = 0V, \overline{SD} = 5V$
V <sub>CCUV+</sub>	$V_{\mbox{CC}}$ and $V_{\mbox{BS}}$ supply undervoltage positive going	8.0	8.9	9.8		
V <sub>BSUV+</sub>	threshold					
VCCUV-	$V_{\mbox{CC}}$ and $V_{\mbox{BS}}$ supply undervoltage negative going	7.4	8.2	9.0		
V <sub>BSUV-</sub>	threshold				l ·	
VCCUVH	Hysteresis	0.3	0.7	-		
VBSUVH						
I <sub>O+</sub>	Output high short circuit pulsed vurrent	120	200	-		$V_{O}$ = 0V, PW $\leq$ 10 $\mu$ s
I <sub>O-</sub>	Output low short circuit pulsed current	250	350	-	mA	$V_O$ =15V,PW $\leq$ 10 $\mu$ s

## Functional Block Diagrams



#### **Lead Definitions**

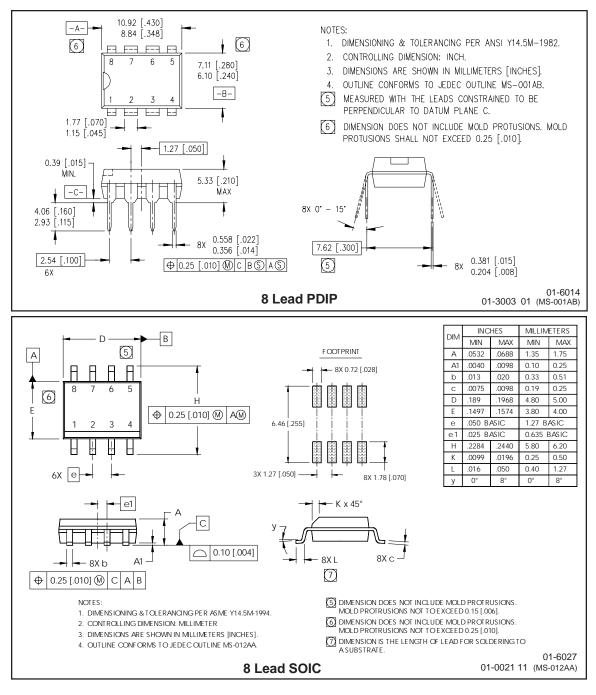
Symbol	Description
IN	Logic input for high and low side gate driver outputs (HO and LO), in phase with HO
DT/SD	Programmable dead-time lead, referenced to VSS. Disables input/output logic when tied to VCC
VB	High side floating supply
HO	High side gate drive output
Vs	High side floating supply return
Vcc	Low side and logic fixed supply
LO	Low side gate drive output
СОМ	Low side return

## Lead Assignments

1       V <sub>CC</sub> V <sub>B</sub> 8         2       IN       HO       7         3       DT/SD       V <sub>S</sub> 6         4       COM       LO       5         8       Lead PDIP       8       1	1       V <sub>CC</sub> V <sub>B</sub> 8         2       IN       HO       7         3       DT/SD       VS       6         4       COM       LO       5         8       Lead       SOIC
IR21091	IR21091(S)

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#### **Case Outlines**





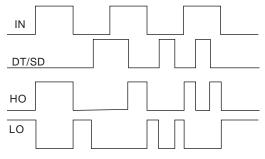


Figure 1. Input/Output Timing Diagram

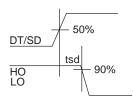
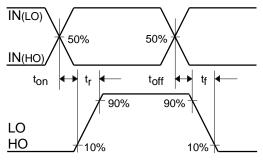


Figure 3. Shutdown Waveform Definitions





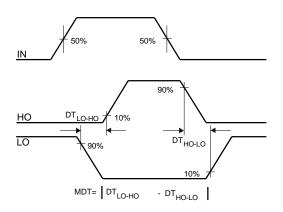


Figure 4. Deadtime Waveform Definitions

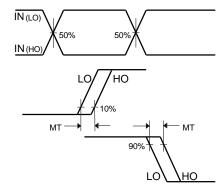
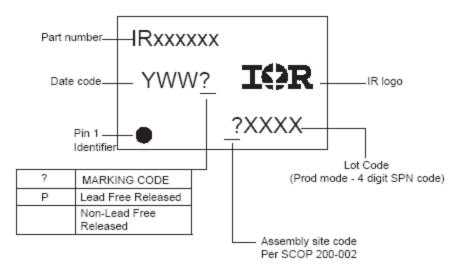


Figure 5. Delay Matching Waveform Definitions

## LEADFREE PART MARKING INFORMATION



#### **Basic Part (Non-Lead Free)**

## Lead-Free Part

8-Lead PDIP IR21091 order IR21091 8-Lead SOIC IR21091S order IR21091S 8-Lead PDIP IR21091 order IR21091PBF 8-Lead SOIC IR21091S order IR21091SPBF

# International

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